Electric Field Assisted Ion Exchange
Strengthening of Borosilicate and Soda
Lime Silicate Glass

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Abstract

In this study, we investigate the effects of electric field assisted ion exchange, EF-IE, on potassium exchange for sodium ion exchanges in the soda borosilicate and soda lime silicate glasses. The results show that applying an electric field with the intensity of 1000 V cm$^{-1}$ for few minutes produces an exchanged layer with a thickness comparable to the conventional chemical strengthening for 4h. There is a critical E-field that increases the mobility and, therefore, the diffusion coefficient of the potassium in the glasses. The increase is, perhaps, related to the evolution of the glass structure due to the penetration of potassium ions under an E-field. Structural studies by micro-Raman spectroscopies reveal that the structure of exchanged layer changes by subjecting to EF-IE; the changes can be explained by the theory of Cation Induced Relaxation of Network, CIRON.

According to the Vickers’ indentations, strong compressive stress is generated in the glass by EF-IE; however, the bending strength improvement is limited because of the presence of large surface defects and the stress distribution inhomogeneity.

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Electric field assisted ion exchange, chemical strengthening, soda lime silicate, borosilicate

Introduction

Glass has a fundamental role in different everyday-life applications such as electronics, cell phones, solar cells, architectural components, and containers, although its typical brittleness. Theoretically, glass is considered as the strongest human-made material; in practice, flaws make it unreliable and weak from the mechanical point of view. Among the several reinforcement techniques proposed during the years, chemical tempering is a straightforward and efficient technique for improving the mechanical performances of alkali silicate glasses.

A compressive stress is produced on the glass surface by chemical tempering, or chemical strengthening, which prevents and limits the formation and propagation of cracks. In a typical process, small sodium or lithium ions are swapped for larger potassium ions diffusing into the glass. Because of the diffusion nature of the process, treatments have to be carried out at relatively high temperature for several hours; for this reason, stress relaxation can occur and make strengthening less efficient than expected. The process can be enhanced by applying ultrasonic waves, microwave heating or electric fields (E-Fields). In particular, electric field assisted ion exchange, EF-IE, has been carried out to modify the refractive index of glass by producing a concentration of elements, like silver or chromium, for optical devices.

The application of an E-field can change the governing mechanism of ion exchange from diffusion to forced migration, thus accelerating the process and modifying the concentration profiles, i.e., its shape and depth. The EF-IE produces inhomogeneous stress distribution in glass that be neglected in optical applications because of the limited depth of exchanged
Nevertheless, the thick exchanged layer required for mechanical applications, which is a must for improving the strength\textsuperscript{5,6}, can change the geometry and, in extreme cases, it can lead to sample failure. Therefore, controlling the depth of the ion-exchanged layer during the process represents a critical and open issue. Nonetheless, particular geometries, i.e. cylinders, can fulfill the required uniformity of compressive stress in the sample.

In the present work, we investigated the E-field assisted ion exchange in alkali borosilicate and soda lime silicate glasses with specific attention to the generated potassium profile, the glass structure evolution, and final strength.

**Experimental procedure**

Soda borosilicate (BS, Fiolax) and soda lime silicate (SLS, Ar-Glas) glass tubes with outer diameter of 9.8 mm and the thickness of 0.6 mm and 1 mm, respectively, were bought from SCHOTT AG to be used in the present work. The glass transition temperature was measured by a differential scanning calorimeter (DSC) (DSC2010, TA Instruments, USA); glass powder with a size lower than 200 µm was prepared by crushing the tubes in an agate mortar; then, the powder was poured into an aluminium pan and placed in the DSC instrument. The samples were heated up to 600°C with a heating rate of 10°C min\textsuperscript{-1}; the glass-transition temperature was estimated according to ASTM E1356 norm\textsuperscript{19}. The glass-transition temperature and the chemical composition are reported in Table 1.

The tubes were ultrasonically cleaned in distilled water, washed with acetone and air-dried.

Ion exchange treatments (IE) were carried out in pure potassium nitrate, Haifa – Eurochemicals (technical grade, ≥99.4%). Conventional chemical tempering was performed by a semi-automatic furnace, TC 20A Lema, Parma, Italy, at 450°C for 4 h. The samples were kept 20 min over the salt bath before and after the treatment to avoid thermal shocks.
Electric field-assisted ion exchange treatments (EF-IE) were performed by a modified chemical tempering furnace, TC 20S Lema, Parma, Italy. The salt bath temperature was kept at 400±10°C during the treatment. The electrical field was varied between 100 V cm⁻¹ to 2000 V cm⁻¹ by a power supply, DLM 600 Sorensen; the current density limit was fixed at 8 mA cm⁻² to prevent spark formation because of the salt electrolysis near the electrodes. The applied voltage and current were monitored by a digital multimeter (DMM 2000, Keithley, Cleveland, USA); a schematic of the setup used for samples preparations is drawn in Figure 1.

Borosilicate glass samples were subjected to the electric field for duration as long as 10 min, while soda lime silicate tubes were treated by applying the field for 5 min because of the shattering of samples, which is observed for longer treatments. The glass resistivity variation against the applied electric field was measured by 4-point probe configuration and using time-variant E-fields. The applied voltage was increased step by step, 5 V at each level, and dwelling time of 5 s. The electrodes resistivity in the salt was measured as a function of the electric current; the interference of electrodes, associated with salt electrolysis, was measured and removed from the recorded data according to the following steps. First, the variations of the electrode’s resistance were estimated as a function of electric current until the formed passive oxide layer on the electrodes is destroyed, and the resistivity drops. Then corresponding resistance to the electrodes is removed from the experimental data. The influence of generated gas can be neglected because of its limited production rate due to the applied current density limit (8 mA cm⁻²).

The mechanical strength of the samples was determined in air by four-point bending tests, using spans of 18 mm and 40 mm and loading rate of 1.1 MPa s⁻¹. In this case, the samples were produced using 1000 V cm⁻¹ E-field until the amount of potassium sent into the glass was comparable with that obtained by conventional ion-exchange at 450°C. The surface stress
generated by ion-exchange was estimated indirectly by Vickers indentations produced with 
maximum load of 20 N and dwelling time of 15 s.

The potassium concentration profile was determined on the fracture surface of some tubes 
fragments; such pieces were stuck on an aluminum disc by using conductive carbon paste and 
then slightly coated with Pt-Pd alloy. The potassium concentration profiles were recorded by 
scanning electron microscope (JEOL, JSM5500) equipped with an electron dispersion x-ray 
spectrometer (EDS 2000, IXRF system, USA). The noise of the microprobe analysis was 
filtered by smoothing it with a low pass filter and considering the potassium concentration of 
the raw glass as the baseline, and afterward the experimental data was fitted using a modified 
complementary error function. The chemical composition on the glass surface was also 
measured by EDS on the tubes before and after ion exchange.

Micro-Raman analysis was carried out on temperature under the excitation of 514.5 nm 
line of Ar-Kr gas laser. Spectra were collected from two different points of the samples 
treated under E-field of 2000 V cm⁻¹, using the same experimental setup described in a previous 
work. The spectra collected from the region that underwent ion-exchange near the surface of 
glass are called “Edge”. The other group of spectra was collected from an area in the middle of 
glass, which has been not affected by ion exchange, is called “Bulk”. Spectra that underwent 
ion-exchange, and the region unaffected by the exchange were called “Edge” and “Bulk”, 
respectively. The background of each spectrum was removed, and the spectrum was filtered to 
eliminate the high-frequency noise. The peaks corresponding to vibrational modes of silicon-
oxide tetrahedra occurring in the wavenumbers of 850 to 1300 cm⁻¹ were fitted, and the peak 
integrals were used to calculate the relative distribution of the glass former units.
Results

Figure 2 shows the current density as a function of time in BS samples subjected to the E-fields up to 2000 V cm\(^{-1}\) with a current density limit equal to 8 mA cm\(^{-2}\); the treatments were conducted in a molten potassium nitrate bath kept at 400±10°C. The current density, gradually decreasing, is larger for higher applied fields. The current limit is achieved under an electric field of 2000 V cm\(^{-1}\). The current density is proportional to the E-field intensity and the inverse of glass resistance; one can conclude that the current density decrease is due to the larger resistance of the exchanged surface layer.

The evolution of current density with time for SLS tubes, which are treated with the same condition to BS glass, is reported in Figure 3. The behavior is quite similar to that observed in borosilicate glass although the current limit is reached at 1000 V cm\(^{-1}\). SLS glass contains more alkali ions compared to BS one and, therefore, its conductivity and current density are higher. This probably can account for the lower E-field at the current limit.

The molar ratio between potassium oxide and the total amount of alkali oxides (Na and K), K\(_2\)O/(K\(_2\)O+Na\(_2\)O), on the glass surface after EF-IE is shown in Table 2. The molar ratio of the raw glass and of tubes immersed in the salt at 450°C for 5 min or treated by conventional ion exchange is shown for comparison. We see that potassium completely replaces sodium on the external surface of EF-IE samples. A limited amount of potassium can be detected on the inner surface of the glass, which is probably related to the limited diffusion of potassium into the glass during the process.

The potassium concentration profiles measured in BS samples subjected to EF-IE are shown in Figure 4; the experimental data were smoothed and fitted by a modified complementary error which will be discussed later on (Eq. 1). The curves resemble a step-like profile and the
depth increases with the applied E-field. The profiles can be divided into three main regions: a
first region, where potassium is constant and maximum, is followed by a second one where the
concentration suddenly decreases to the raw glass situation. The exchanged layer
thickness reaches 15 µm after subjecting to E-field of 1000 V cm⁻¹ for 600 s, which is
considerably deeper than the layer produced by conventional ion exchange at 450°C for 4 h,
shown in Figure 4.

Figure 5 shows the potassium concentration profiles in SLS, the shape being similar to that
revealed in BS glass. In this case, the E-field with the intensity of 100 V cm⁻¹ is not strong
enough to produce the constant concentration zone in 300 s. By applying E-fields stronger
than 500 V cm⁻¹, it is possible to produce an exchanged layer with a depth comparable to that
obtained by chemical strengthening at 450°C for 4 h, equal to ≈15 µm.

The concentration, \( C_K(x,t) \), reported in Figure 4 and Figure 5 can be fitted by a
modified complementary error function as suggested in a previous work [18]:

\[
C_K(x,t) = \frac{C_K^S}{2} \text{erfc}\left(\frac{x - \left(\frac{DEt}{k_B T}\right)}{\sqrt{Dt}}\right) \tag{1}
\]

where \( x \) is the distance from the surface, \( t \) the time, \( DE \) the distance from the surface and
time, respectively, \( C_K^S \) the surface concentration, \( D \) the diffusion coefficient of potassium, \( E \)
is the E-field intensity, \( T \) the absolute temperature and \( k_B \) the Boltzmann constant.

The diffusion coefficient, estimated by Eq. 1 for different applied E-Fields, is shown in Figure
6. For BS glass the coefficient is around 6×10⁻¹² cm² s⁻¹ for E-field up to 1000 V cm⁻¹; then it
increases up to 12×10⁻¹² cm² s⁻¹ for E-field with intensity of 2000 V cm⁻¹ is applied. The
diffusion coefficient for SLS glass is larger than BS samples; the coefficient is around 10×10⁻¹² cm² s⁻¹ for very limited E-field (up to 200 V cm⁻¹) for the E-fields of 100 and
200 V cm⁻¹. We see that the coefficient increases with the applied E-field increase and it
becomes then it increases up to $20 \times 10^{-12}$ cm$^2$ s$^{-1}$ when the E-field is at 1000 V cm$^{-1}$ or larger.

The diffusion coefficient is related to the mobility of ions, $\mu$, through Einstein relation, $D=\mu k_B T$. Therefore, the different ion mobility in the two considered glasses can be accounted for explaining the observed differences in the diffusion coefficient.

Figure 7 shows the glass resistivity evolution as a function of the “actual E-field,” which is estimated by removing the interference of electrodes. We see that the resistivity reaches a constant value for limited E-field intensities in SLS glass, while it is an increasing function of the E-field for BS glass; this is probably related to the different required activation energy for diffusion and structural evolution of glasses. It must be mention that the BS behavior might change under stronger E-field which can not be applied by using the mentioned power supply. The BS glass behavior under strong E-fields is a fundamental question needed to be answered.

Typical Vickers indentation patterns produced using load of 20 N are shown in Figure 8. The compressive stress generated by ion exchange at 450°C for 4 h inhibits the crack propagation. In glasses subjected to EF-IE, a relatively high compressive stress is generated on the surface that prevents also the nucleation of cracks.

The bending strength of samples subjected to EF-IE and conventional ion-exchange is reported in Table 3. Ion exchange clearly improves the mechanical resistance of the glasses. The BS glass contains less sodium than SLS (Table 1); therefore, surface compression produced by IE in BS is lower than in SLS. The strength of BS samples subjected to EF-IE is larger than in conventionally treated ones. Conversely, for SLS tubes, EF-IE is less efficient than conventional treatment, if we consider the final strength as a gauge of ion-exchange efficiency.

Additional features regarding the strength can be pointed out from the Weibull distributions shown in Figure 9; the strength corresponding the failure probability, $F$, of 63.2% which is known as the characteristic strength, is also reported in the plots. The characteristic strength of
BS glass increases from 72 MPa to 121 MPa after ion exchange; EF-IE improves the characteristic strength a bit more, up to 141 MPa although failure resistance is more scattered. Conventional ion exchange is also beneficial for SLS tubes, the characteristic strength increasing from 420 MPa to 133 MPa, much more than EF-IE.

Discussion

The chemical strengthening efficiency depends on the stress production by stuffing larger potassium ions into the glass. The EF-IE produces potassium concentration profiles with the same depth as conventional ion exchange and a slightly higher K concentration. One may expect that the EF-IE strengthening is more efficient than the conventional strengthening because of the larger compression on the surface, as we can see in the case of BS glass. Conversely, the SLS tubes treated by EF-IE show significantly lower strength compared to the SLS samples treated by conventional ion exchange strengthening, but EF-IE strengthening of SLS tubes is not as influential as that expected from BS samples, especially when it is compared with conventional ion exchange strengthening. The distinction between the ion mobility and the diffusion of ions, which is probably related to the structural evolutions, may be accounted for the limited improvement of SLS glass using EF-IE.

E-field pushes the alkali ions into the glass surface and an E-field, strong enough, can also change the governing mechanism of mass transfer. This occurs for example, in SLS samples treated under E-field in excess of 100 V cm⁻¹ (Figure 2) sodium ions being completely replaced by potassium. Ingram et al. have reported that the exchanged layer has a higher resistivity compared to the raw glass; consequently, the glass resistivity increases by increasing the depth of exchanged layer and the current density decreases. The formation of an exchanged layer, which
is more resistive, generates an inhomogeneous distribution of the E-field in the glass, the inner surface being subjected to a weaker E-field; this is responsible for the limited potassium diffusion into the glass on the inner surface of tubes (Table 2). The glass resistivity is the representative of the mobility of alkali ions under E-fields and, hence, the diffusion coefficient.

The glass subjected to ion exchange can be considered as a bilayer material composed of bulk glass (i.e. the raw glass) and the exchanged layer. The resistivity can be described by an equivalent electrical circuit consisting of two resistors in series; a schematic drawing of the circuit is shown in Figure 12. The total resistivity of sample, $R_{\text{total}}$, is a function of each layer thickness and resistivity, which can be expressed as:

$$R_{\text{total}} = xR_{\text{exch}} + (1 - x)R_{\text{bulk}}$$  \hspace{1cm} (2)

where $R_{\text{exch}}$ and $R_{\text{bulk}}$ are the resistivity of the exchanged layer and of the bulk, respectively. $x$ is the ratio between the exchanged layer and the glass thickness. The resistivity of the exchanged layer can be considered constant because of the constant concentration of potassium; therefore, the total resistivity of the exchanged layer and the total glass can be calculated as:

$$R_{\text{exch}} = R_{\text{bulk}} + \Delta R$$  \hspace{1cm} (3)

$$R_{\text{total}} = R_{\text{Na}}(x \frac{\Delta R}{R_{\text{Na}}} + 1)$$  \hspace{1cm} (4)

Considering the actual thickness of exchanged layer, which is less than one percent of the overall glass thickness, the influence of the exchanged layer in Eq. 4 can be neglected and, therefore, the resistivity of glass can be assumed equal to the resistivity of the bulk glass subjected to ion exchange. At constant temperature, the resistivity of glass containing only monovalent cations is a function of the E-field, $E$, and the drift velocity, $v$, of cation:

$$R = \frac{\phi_v}{E}$$  \hspace{1cm} (5)
where $\varphi$ is a proportionality constant depending on the mobility of ions which can be estimated from:

$$
\varphi = \frac{C \nu F^2 k_B}{e} \quad (6)
$$

where $\nu$ is the drift velocity of the charge carriers in the glass, $F$ is the Faraday’s constant, $R$ the perfect gas constant, $T$ temperature, $C$ the ratio of charge carriers (sodium ions) $n$, over the total amount of mobile cations, $N_2$; $C$ can be considered equal to $1$ here. $e$ is the electron charge=$1e$, $k_B$ Boltzmann constant. Due to the constant temperature of treatments, $\varphi$ can be considered constant.

According to Eq. 5, glass resistivity is a linear function of the applied $E$-field unless the drift velocity of ions changes non-linearly with the $E$-field, which accounts for non-ohmic behavior.

Figure 6 shows that the resistivity of SLS glass becomes constant at a certain $E$-field. Conversely, the resistivity of BS continuously increases although with decreasing rate. This is indicative of a non-linear increase of drift velocity with $E$-field. Similar behavior has been previously reported in silver-containing glasses subjected to $E$-field, silver clusters producing channels for ion conduction\textsuperscript{15, 36, 37, 38}. The formation of such channels is probably responsible for the larger drift velocity and, therefore, for the abrupt increase of potassium diffusion coefficient at certain $E$-field as shown in Figure 6. The movement of larger potassium ions via sodium sites in the silicate glass structure might occur with breaking and rearranging of the bonds through cation-induced-relaxation-of-network (CIRON) as proposed by Ingram et. al.\textsuperscript{39} It is known that the alkali ion transport through the glass occurs by rearranging the $Q_n$ species\textsuperscript{22, 39}. Vareshneya A.K. suggested that the movement of invading potassium ions and the accommodation of them in the sodium sites occur by bending or stretching of the bonds surrounding the host site beyond the strain limit. This causes a permanent change in the glass structure that might be responsible for the facilitated ions mobility and, consequently, the diffusion coefficient\textsuperscript{6, 22, 39}, which can be described as $Q_2\leftrightarrow Q_4\leftrightarrow 2Q_3$ (Table 4).\textsuperscript{40} The new glass
structure contains more Q₃ species, which are probably oriented to facilitate the alkali ions movement. The E-field of sufficient intensity can provide the required energy for breaking and reforming of the bonds.

It is possible to observe the evolution of glass structure from comparing the Raman spectra collected from the layer undergone the Na/K exchange, called edge, and the bulk glass, which is not influenced by the invading potassium ions. In order to ease the comparison of the collected spectra, the background noise and fluorescence are removed. Figure 11 shows the final Raman spectra in the 800 to 1250 cm⁻¹ region. The peak envelope in this window is corresponding to the region where the Raman peaks are mainly associated with the silicon-oxygen stretching vibrations in silicate Q₄ units. This region is a convolution of different peaks mainly corresponding to the Q₂, Q₃, and Q₄ species. We see that the peak shape of exchanged layer is different from the bulk in the BS sample which reveals a change of the degree of connectivity of the glass network (concentration of Q₄ units). In the case of SLS glass, the location of the peak maximum shifts to the higher wavenumbers. Such changes of Raman spectra unveil the generation of a new structure in the ion-exchanged layer. More studies are required in order to get a clear picture of the structural evolution during ion exchange and possible transitions such as phase separation particularly in the case of borosilicate glasses. Phase separation causes an abrupt change in glass resistivity of samples because of the production of two different phases (glasses); this phenomenon appears as a spontaneous change in the current density curves of samples. Since the current density of samples does not change in such a fashion, it is fair to state that no phase separations occur in these treatments.

It seems that an E-field, sufficiently strong, can provide the required energy for the possible structural modifications. The current passing through the glass can also increase the temperature because of Joule heating and cause structural and stress relaxation. Nevertheless, due to
the limited thickness of the tubes, 0.6 mm (BS) and 1 mm (SLS), the sample temperature can
be considered constant and in equilibrium with the molten salt, at a temperature below the
stress relaxation temperature. The limited cracking after Vickers indentations (Figure 9) also
confirms the presence of surface compression in samples subjected to EF-IE.

The strengthening efficiency depends on the amount of replaced alkali ions on the surface
\(^2, \^6\); since SLS glass has twice sodium than BS, one should expect larger compressive stress and
higher strength in the former; this matches reasonably with the obtained experimental
data results from Vickers' indentations. It is worth mentioning that some original defects are
larger than the exchange layer and can not be completely "reinforced" by IE process; such
flaws are responsible for limited strength values and account for the small Weibull modulus
estimated for EF-IE samples. It should be noted that only the exterior surface of the tubes was
subjected to EF-IE; therefore, the influence of original defects on the interior surface is crucial.

According to Vickers indentations results (Figure 8), there is strong compression on the surface
of EF-IE samples and the thickness of the exchanged layer is comparable to that produced by
IE; one can conclude that the limited strength of SLS samples treated by EF-IE is rather related
to correlates with the non-symmetric stress distribution along the thickness than a thin
compression layer in the surface-insufficient surface compression. As the outer surface is
strongly compressed, the inner one undergoes under a significant, if not huge, tension;
consequently, the glass becomes very vulnerable to the defects of the inner surface and during
bending tests, failure can start from the inner surface at relatively small loads. \(^11\) This also
explains the lower Weibull modulus calculated for samples treated by EF-IE.
Summary and Conclusions

Electric field assisted ion exchange, EF-IE, was used to accelerate replacing sodium by potassium on the surface of soda-lime silicate and soda borosilicate glasses. EF-IE produces step-like concentration profiles in glasses with a depth comparable to the conventional ion exchange in a significantly shorter time. The diffusion coefficient of potassium in glass changes when it is subjected to E-fields; it seems that there is a critical E-field that can increase the mobility of ions significantly; this phenomenon needs to be studied in detail. During the EF-IE, the glass structure changes by rearranging the Qn species according to $Q_2 + Q_4 \leftrightarrow 2Q_3$; this facilitates the ion movement. EF-IE produces a strong compressive stress on the surface of glass that prevents crack nucleation during Vickers’ indentation; however, in this study, the strength augmentation is probably hindered by the presence of large surface defects.

The electric field assisted ion exchange can be used in principle to produce a strong compressive stress in soda lime silicate and soda borosilicate glass; however, the process should be accurately controlled. This requires a deeper look into the stress build-up of stress in glass by EF-IE; moreover, procedures for balancing the residual stress such as inverting the polarization should be proposed and investigated.

Acknowledgements

We appreciate the assistance of Dr. Marco Giarola for the micro-Raman measurements and his help with the characterisation of samples.
References


Figure 1 Schematic of the experimental setup for sample preparation and the instrumentation for monitoring and controlling the electric field.

Figure 2 Current density as a function of time in BS tubes subjected to different E-fields (current density limit: 8 mA cm²).

Figure 3 Current density as a function of time in SLS tubes subjected to different E-fields (current density limit: 8 mA cm²).

Figure 4 Relative potassium concentration profiles for BS tubes subjected to electric field-assisted ion exchange (EF-IE) at 400°C, and conventional ion exchange at 450°C for 4h.

Figure 5 Relative potassium concentration profiles for SLS tubes subjected to electric field-assisted ion exchange (EF-IE) at 400°C, and conventional ion exchange at 450°C for 4h.

Figure 6 Diffusion coefficient estimated for variable electric fields for samples treated at 400°C. (a) borosilicate, (b) soda lime silicate glass.

Figure 7 Evolution of resistivity as a function of applied electric field for glasses immersed in potassium nitrate at 400°C; The second x-axis presents the applied E-field regarding the power supply output voltage.

Figure 8 Vickers indentations on glasses, borosilicate and soda lime silicate glass: (a) and (d) as cut, (b) and (e) conventional ion exchanged, (c) and (f) exchanged under E-field (2000 V cm⁻¹).
Figure 9 Weibull distributions of: (a) BS; (b) SLS glass. Fitting lines used for the determination of Weibull modulus (m) and specific characteristic strength (reported values) are shown (F is the failure probability).

Figure 10 Equivalent circuit model of a glass subjected to electric field assisted ion exchange.

Figure 11 Micro-Raman spectra of glasses subjected to EF-IE (2000 V cm$^{-1}$) in 800-1250 cm$^{-1}$ region: (a) borosilicate glass, (b) soda lime silicate glass.
Table 1 Chemical composition and transition temperature of the glass tubes used in this work.

<table>
<thead>
<tr>
<th>Chemical composition (wt%)</th>
<th>Glass transition temperature</th>
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<tbody>
<tr>
<td>SiO₂</td>
<td>B₂O₃</td>
</tr>
<tr>
<td>Borosilicate (Fiolax)</td>
<td>75.0</td>
</tr>
<tr>
<td>Soda lime silicate (AR-Glas)</td>
<td>69.0</td>
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</table>
Table 2 $K_2O/(Na_2O+K_2O)$ molar ratio (%) on the tubes surface in different conditions: as bought raw glass, after ion exchange (IE), simply kept in the salt bath for 5 min and after E- Field assisted ion exchange (EF-IE)

<table>
<thead>
<tr>
<th>Raw glass</th>
<th>IE</th>
<th>5 min</th>
<th>EF-IE</th>
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</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td></td>
<td>Outer surface</td>
</tr>
<tr>
<td>Borosilicate</td>
<td>0</td>
<td>90</td>
<td>60</td>
</tr>
<tr>
<td>Soda lime silicate</td>
<td>10</td>
<td>80</td>
<td>80</td>
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</table>
Table 3 Average bending strength and corresponding standard deviation for raw glass tubes and samples subjected to conventional ion exchange (IE) and E-Field assisted ion exchange (EF-IE).

<table>
<thead>
<tr>
<th></th>
<th>Borosilicate</th>
<th>Soda Lime Silicate</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Raw glass</td>
<td>IE IE-IE</td>
</tr>
<tr>
<td>Average strength</td>
<td>64</td>
<td>122 137</td>
</tr>
<tr>
<td>(MPa)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Standard deviation</td>
<td>18</td>
<td>17 36</td>
</tr>
<tr>
<td>(MPa)</td>
<td></td>
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Table 4 Relative concentration of Qn species in glass estimated from Raman spectra in Figure 9; numbers in parentheses show the random error cumulated upon fitting.

<table>
<thead>
<tr>
<th></th>
<th>Soda-Borosilicate</th>
<th>Soda-Lime Silicate</th>
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</thead>
<tbody>
<tr>
<td></td>
<td>Bulk</td>
<td>Edge</td>
</tr>
<tr>
<td>Q₁</td>
<td>10.6(0.4)</td>
<td>8.4(0.8)</td>
</tr>
<tr>
<td>Q₂</td>
<td>29.9(0.9)</td>
<td>24.9(0.3)</td>
</tr>
<tr>
<td>Q₃</td>
<td>37.0(0.2)</td>
<td>44.7(0.1)</td>
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<tr>
<td>Q₄</td>
<td>22.5(0.4)</td>
<td>22.1(0.0)</td>
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